IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Xian J. Ning

Attorney Docket: 01 P 7422 US 01

Filed: May 14, 2001

Examiner:

TBD

Serial No.: TBD

Art Unit:

TBD

For: Design of Lithography Alignment and Overlay Measurement Marks on CMP Finished Damascene Surface

INFORMATION DISCLOSURE STATEMENT

Assistant Commissioner For Patents

Washington, DC 20231

Dear Sir:

MAILING CERTIFICATE

Thereby certify that this correspondence is being deposited with the United States Postal Service as Express Mail No. EL. 842426900 US addressed to: Assistant Commissioner for

Karen Fabrilies

5/14/0 |

Applicant wishes to bring to the attention of the Patent and Trademark Office the information noted on the enclosed PTO-1449 that may be considered material to the examination of the above-identified application.

No fee is due at this time as this statement is being filed with the application.

Respectfully submitted.

Steven 11. Stater

Attorney for Applicant

Reg. No. 35,361

FORM PTO- (REV. 7-80)		PATE: F DOCUMENTS C	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE CUMENTS CITED BY APPLICANT Use several sheets if necessary)			KET NO. 1 US 01	SERIAL NO.	U.S. PTO 854760	# 1 4 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
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ΑO Chi-Tzung Wang, et al., Pad Wear Analysis in CMP; 1999 VMIC Conference; 1999 iMIC 109/99/0267(c) ΑP Srini Raghavan, et al., Elecrochemical Behavior of Copper and Tantalum in Silica Slurries Containing Hydroxylamine, 1999 VMIC Conference; 1999 IMIC 109/99/0619(c) AQRajeev Bajaj, et al., Manufacturability Considerations and Approaches for Development of a Copper CMP Process; 1999 VMIC Conference, 1999 MIC 109/99/0144(c)

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

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